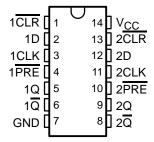
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- Controlled Baseline
 - One Assembly/Test Site, One Fabrication Site
- Extended Temperature Performance of -55°C to 125°C
- Enhanced Diminishing Manufacturing Sources (DMS) Support
- Enhanced Product-Change Notification
- Qualification Pedigree[†]
- EPIC™ (Enhanced-Performance Implanted CMOS) Process
- Operating Range 2-V to 5.5-V V_{CC}
- Latch-Up Performance Exceeds 250 mA Per JESD 17
- ESD Protection Exceeds 2000 V Per MIL-STD-883, Method 3015; Exceeds 200 V Using Machine Model (C = 200 pF, R = 0)

† Component qualification in accordance with JEDEC and industry standards to ensure reliable operation over an extended temperature range. This includes, but is not limited to, Highly Accelerated Stress Test (HAST) or biased 85/85, temperature cycle, autoclave or unbiased HAST, electromigration, bond intermetallic life, and mold compound life. Such qualification testing should not be viewed as justifying use of this component beyond specified performance and environmental limits.

D OR PW PACKAGE (TOP VIEW)



description/ordering information

The SN74AHC74 dual positive-edge-triggered device is a D-type flip-flop.

A low level at the preset (PRE) or clear (CLR) inputs sets or resets the outputs, regardless of the levels of the other inputs. When PRE and CLR are inactive (high), data at the data (D) input meeting the setup time requirements is transferred to the outputs on the positive-going edge of the clock pulse. Clock triggering occurs at a voltage level and is not directly related to the rise time of the clock pulse. Following the hold-time interval, data at the D input can be changed without affecting the levels at the outputs.

ORDERING INFORMATION

TA	T _A PACKAGE [‡]		ORDERABLE PART NUMBER	TOP-SIDE MARKING
55°C to 135°C	SOIC - D	Tape and reel	SN74AHC74MDREP	AHC74MEP
–55°C to 125°C	TSSOP - PW	Tape and reel	SN74AHC74MPWREP	AHC74EP

[‡] Package drawings, standard packing quantities, thermal data, symbolization, and PCB design guidelines are available at www.ti.com/sc/package.



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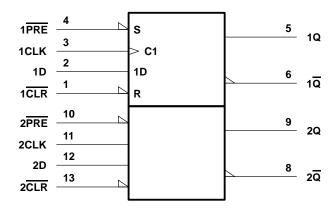
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FUNCTION TABLE (each flip-flop)

	INP	OUTPUTS			
PRE	CLR	CLK	D	Q	Q
L	Н	Х	Х	Н	L
Н	L	X	Χ	L	Н
L	L	X	Χ	н†	H [†]
Н	Н	\uparrow	Н	Н	L
Н	Н	\uparrow	L	L	Н
Н	Н	L	Х	Q ₀	\overline{Q}_0

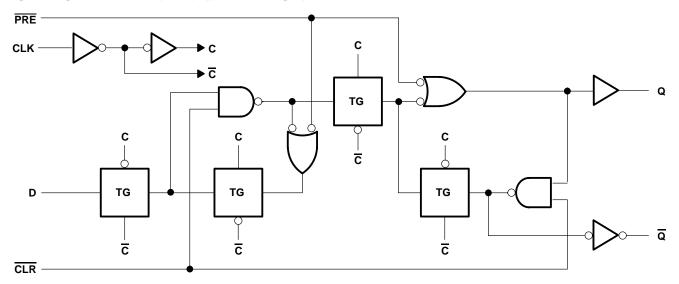
[†]This configuration is nonstable; that is, it does not persist when PRE or CLR returns to its inactive (high) level.

logic symbol‡



[‡]This symbol is in accordance with ANSI/IEEE Std 91-1984 and IEC Publication 617-12.

logic diagram, each flip-flop (positive logic)





SN74AHC74-EP DUAL POSITIVE-EDGE-TRIGGERED D-TYPE FLIP-FLOP WITH CLEAR AND PRESET

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absolute maximum ratings over operating free-air temperature range (unless otherwise noted)†

Supply voltage range, V _{CC}	0.5 V to 7 V
Input voltage range, V _I (see Note 1)	0.5 V to 7 V
Output voltage range, VO (see Note 1)	
Input clamp current, I _{IK} (V _I < 0)	
Output clamp current, I _{OK} (V _O < 0 or V _O > V _{CC})	±20 mA
Continuous output current, $I_O(V_O = 0 \text{ to } V_{CC})$	±25 mA
Continuous current through V _{CC} or GND	±50 mA
Package thermal impedance, θ_{JA} (see Note 2): D package .	86°C/W
PW package	113°C/W
Storage temperature range, T _{Stq}	

[†] Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

recommended operating conditions (see Note 3)

			MIN	MAX	UNIT
VCC	Supply voltage		2	5.5	V
		V _{CC} = 2 V	1.5		
V_{IH}	High-level input voltage	V _{CC} = 3 V	2.1		V
		$V_{CC} = 5.5 V$	3.85		
	$ V_{CC} = 2 \text{ V} $ Low-level input voltage $ V_{CC} = 3 \text{ V} $			0.5	
V_{IL}				0.9	V
		$V_{CC} = 5.5 \text{ V}$		1.65	
٧ _I	Input voltage		0	5.5	٧
٧o	Output voltage		0	VCC	V
		V _{CC} = 2 V		-50	μΑ
IOH	High-level output current	$V_{CC} = 3.3 \text{ V} \pm 0.3 \text{ V}$		-4	mA
		$V_{CC} = 5 V \pm 0.5 V$		-8	IIIA
		V _{CC} = 2 V		50	μΑ
IOL	Low-level output current	$V_{CC} = 3.3 \text{ V} \pm 0.3 \text{ V}$		4	mA
		$V_{CC} = 5 V \pm 0.5 V$		8	ША
Δt/Δν	$V_{CC} = 3.3 \text{ V} \pm 0.3 \text{ V}$			100	ns/V
Δι/ΔV	Input transition rise or fall rate	$V_{CC} = 5 V \pm 0.5 V$		20	115/V
T _A	Operating free-air temperature		-55	125	°C

NOTE 3: All unused inputs of the device must be held at V_{CC} or GND to ensure proper device operation. Refer to the TI application report, Implications of Slow or Floating CMOS Inputs, literature number SCBA004.



NOTES: 1. The input and output voltage ratings may be exceeded if the input and output current ratings are observed.

^{2.} The package thermal impedance is calculated in accordance with JESD 51-7.

SN74AHC74-EP DUAL POSITIVE-EDGE-TRIGGERED D-TYPE FLIP-FLOP WITH CLEAR AND PRESET

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electrical characteristics over recommended operating free-air temperature range (unless otherwise noted)

PARAMETER	TEST CONDITIONS	Vaa	T	_ = 25°C	;	MIN	MAX	UNIT
PARAMETER	TEST CONDITIONS	VCC	MIN	TYP	MAX	IVIIIN	WAX	ONT
		2 V	1.9	2		1.9		
	I _{OH} = -50 μA	3 V	2.9	3		2.9		
Voн		4.5 V	4.4	4.5		4.4		V
	$I_{OH} = -4 \text{ mA}$	3 V	2.58			2.48		
	$I_{OH} = -8 \text{ mA}$	4.5 V	3.94			3.8		
		2 V			0.1		0.1	
	I _{OL} = 50 μA	3 V			0.1		0.1	
VOL		4.5 V			0.1		0.1	V
	I _{OL} = 4 mA	3 V			0.36		0.5	
	I _{OL} = 8 mA	4.5 V			0.36		0.5	
lį	V _I = 5.5 V or GND	0 V to 5.5 V			±0.1		±1	μΑ
Icc	$V_I = V_{CC}$ or GND, $I_O = 0$	5.5 V			2		20	μΑ
C _i	$V_I = V_{CC}$ or GND	5 V		2	10		·	pF

timing requirements over recommended operating free-air temperature range, V_{CC} = 3.3 V \pm 0.3 V (unless otherwise noted) (see Figure 1)

			T _A = 25°C		MIN	MAX	UNIT	
		_	MIN	MAX	IVIIIN	WAA	UNIT	
t _w	Pulse duration	PRE or CLR low	6		7		no	
ιW	ruise auralion	CLK	6		7		ns	
	Satura tima hafara CLIVA	Data	6		7			
t _{su}	Setup time before CLK↑	PRE or CLR inactive	5		5		ns	
th	Hold time, data after CLK↑		0.5		0.5		ns	

timing requirements over recommended operating free-air temperature range, V_{CC} = 5 V \pm 0.5 V (unless otherwise noted) (see Figure 1)

		T _A = 25°C		MIN	MAX	UNIT	
			MIN MAX		IVIIIN	IVIAA	UNIT
Γ.	Pulse duration	PRE or CLR low	5		5		50
t _W	ruise duration	CLK	5		5		ns
	Catura tima hafara CLV [↑]	Data	5		5		no
t _{su}	Setup time before CLK↑	PRE or CLR inactive	3		3		ns
t _h	Hold time, data after CLK↑		0.5		0.5		ns

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switching characteristics over recommended operating free-air temperature range, V_{CC} = 3.3 V \pm 0.3 V (unless otherwise noted) (see Figure 1)

PARAMETER	FROM	то	LOAD	T,	Վ = 25° C	;	MIN	MAX	UNIT
PARAMETER	(INPUT)	(OUTPUT) CAPACITANCE		MIN	TYP	MAX	IVIIIV	IVIAA	UNIT
f			C _L = 15 pF	80	125		70		MHz
fmax			C _L = 50 pF	50	75		45		IVITIZ
t _{PLH}	<u> </u>	0	C _L = 15 pF		7.6	12.3	1	14.5	ns
t _{PHL}	PRE or CLR	Q or Q	OL = 13 pi		7.6	12.3	1	14.5	115
t _{PLH}	CLK	0 - - - -	Q or \overline{Q} $C_L = 15 pF$		6.7	11.9	1	14	ns
t _{PHL}	CLK	Q or Q			6.7	11.9	1	14	10
tPLH	<u> </u>	0	C _I = 50 pF		10.1	15.8	1	18	ns
t _{PHL}	PRE or CLR	Q or $\overline{\mathbb{Q}}$	CL = 30 pr		10.1	15.8	1	18	10
t _{PLH}	CLK	Q or $\overline{\mathbb{Q}}$	C _L = 50 pF		9.2	15.4	1	17.5	ns
t _{PHL}	CLK	Q OI Q	CL = 50 pr		9.2	15.4	1	17.5	115

switching characteristics over recommended operating free-air temperature range, V_{CC} = 5 V \pm 0.5 V (unless otherwise noted) (see Figure 1)

PARAMETER	FROM	то	LOAD	T,	գ = 25°C	;	MIN	MAX	UNIT
FARAMETER	(INPUT)	(OUTPUT) CAPACITANCE		MIN	TYP	MAX	IVIIIV	IVIAA	ONIT
4			C _L = 15 pF	130	170		110		MHz
fmax			C _L = 50 pF	90	115		75		IVITIZ
t _{PLH}	DDE OLD	0	C _I = 15 pF		4.8	7.7	1	9	ns
t _{PHL}	PRE or CLR	Q or \overline{Q}	OL = 13 bi		4.8	7.7	1	9	1115
t _{PLH}	CLK	Q or \overline{Q}	C _L = 15 pF		4.6	7.3	1	8.5	ns
t _{PHL}	OLK				4.6	7.3	1	8.5	110
^t PLH	PRE or CLR	Q or Q	C _L = 50 pF		6.3	9.7	1	11	ns
^t PHL	PRE OF CLR	Q or Q	CL = 30 pr		6.3	9.7	1	11	115
^t PLH	CLK	Q or Q	C _L = 50 pF		6.1	9.3	1	10.5	ns
^t PHL	CLK	Q 01 Q	CL = 30 pr		6.1	9.3	1	10.5	115

noise characteristics, $V_{CC} = 5 \text{ V}$, $C_L = 50 \text{ pF}$, $T_A = 25^{\circ}\text{C}$ (see Note 4)

	PARAMETER	MIN	MAX	UNIT
V _{OL(P)}	Quiet output, maximum dynamic V _{OL}		0.8	V
V _{OL(V)}	Quiet output, minimum dynamic V _{OL}		-0.8	V
V _{OH(V)}	Quiet output, minimum dynamic V _{OH}	4.7		V
V _{IH(D)}	High-level dynamic input voltage	3.5		V
V _{IL(D)}	Low-level dynamic input voltage		1.5	V

NOTE 4: Characteristics are for surface-mount packages only.

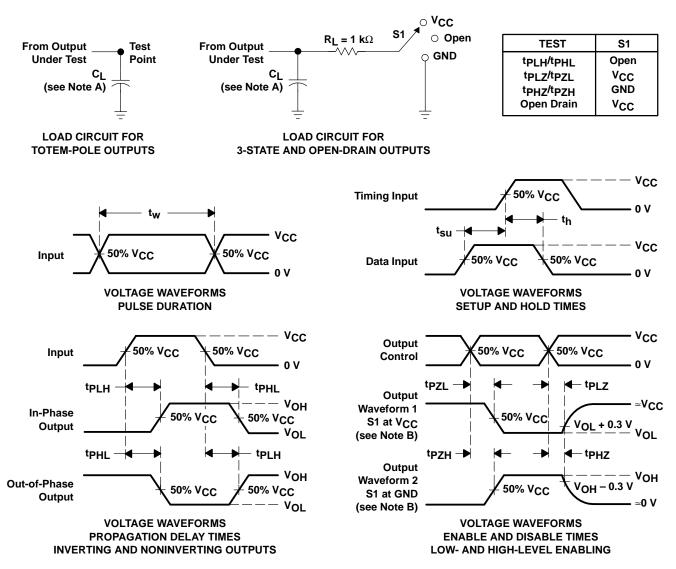
operating characteristics, $V_{CC} = 5 \text{ V}$, $T_A = 25^{\circ}\text{C}$

	PARAMETER	TEST CONDITIONS	TYP	UNIT
Γ	Power dissipation capacitance	No load, f = 1 MHz	32	pF



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PARAMETER MEASUREMENT INFORMATION



NOTES: A. C_L includes probe and jig capacitance.

- B. Waveform 1 is for an output with internal conditions such that the output is low except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high except when disabled by the output control.
- C. All input pulses are supplied by generators having the following characteristics: PRR \leq 1 MHz, $Z_O = 50 \Omega$, $t_f \leq 3$ ns. $t_f \leq 3$ ns.
- D. The outputs are measured one at a time with one input transition per measurement.

Figure 1. Load Circuit and Voltage Waveforms



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PACKAGING INFORMATION

Orderable part number	Status	Material type	Package Pins	Package qty Carrier	RoHS	Lead finish/ Ball material	MSL rating/ Peak reflow	Op temp (°C)	Part marking (6)
	` ,	` ,			, ,	(4)	(5)		, ,
SN74AHC74MDREP	Active	Production	SOIC (D) 14	2500 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-55 to 125	AHC74MEP
SN74AHC74MDREP.A	Active	Production	SOIC (D) 14	2500 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-55 to 125	AHC74MEP
SN74AHC74MPWREP	Obsolete	Production	TSSOP (PW) 14	-	-	Call TI	Call TI	-55 to 125	AHC74EP
V62/03652-01YE	Active	Production	SOIC (D) 14	2500 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-55 to 125	AHC74MEP

⁽¹⁾ Status: For more details on status, see our product life cycle.

Multiple part markings will be inside parentheses. Only one part marking contained in parentheses and separated by a "~" will appear on a part. If a line is indented then it is a continuation of the previous line and the two combined represent the entire part marking for that device.

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⁽²⁾ Material type: When designated, preproduction parts are prototypes/experimental devices, and are not yet approved or released for full production. Testing and final process, including without limitation quality assurance, reliability performance testing, and/or process qualification, may not yet be complete, and this item is subject to further changes or possible discontinuation. If available for ordering, purchases will be subject to an additional waiver at checkout, and are intended for early internal evaluation purposes only. These items are sold without warranties of any kind.

⁽³⁾ RoHS values: Yes, No, RoHS Exempt. See the TI RoHS Statement for additional information and value definition.

⁽⁴⁾ Lead finish/Ball material: Parts may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

⁽⁵⁾ MSL rating/Peak reflow: The moisture sensitivity level ratings and peak solder (reflow) temperatures. In the event that a part has multiple moisture sensitivity ratings, only the lowest level per JEDEC standards is shown. Refer to the shipping label for the actual reflow temperature that will be used to mount the part to the printed circuit board.

⁽⁶⁾ Part marking: There may be an additional marking, which relates to the logo, the lot trace code information, or the environmental category of the part.

PACKAGE OPTION ADDENDUM

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◆ Catalog : SN74AHC74

Military : SN54AHC74

NOTE: Qualified Version Definitions:

Catalog - TI's standard catalog product

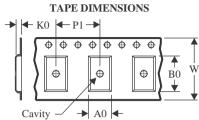
• Military - QML certified for Military and Defense Applications

PACKAGE MATERIALS INFORMATION

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TAPE AND REEL INFORMATION





A0	Dimension designed to accommodate the component width
В0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



*All dimensions are nominal

Device		Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
SN74AHC74MDREP	SOIC	D	14	2500	330.0	16.4	6.5	9.0	2.1	8.0	16.0	Q1

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*All dimensions are nominal

	Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
I	SN74AHC74MDREP	SOIC	D	14	2500	340.5	336.1	32.0

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